Diode Semiconductor Device - Page 1 of 1



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Inclosure Mate Metal	
Overall Length	:
1.138 inches	Which Designed
	Vhich Designed:
Rectifier	14. O
Mounting Facil	ity Quantity:
1 Jaint Fl astnani	
	c Device Engineering Council/jedec/case Outline Designation:
Do-203aa	- 1
Mounting Meth	iou:
Threaded stud	de di
Features Provi	
Hermetically sea	
Overall Width	ACTOSS FIRIS:
0.430 inches	
Thread Size:	
0.190 inches	- Meterial
Semiconducto	r material:
Silicon	In Volto Day Characteristics
	In Volts Per Characteristic:
	peak reverse voltage, peak total value
-	Per Characteristic:
-	forward current, average absolute
-	rating Tempurature Per Measurement Point:
125.0 degrees o	
Thread Series	Designator:
Unf	And Quantity
Terminal Type	
	g and 1 threaded stud
Specification E	
	6425 professional/industrial association specification
Shelf Life:	
N/a	
Unit Of Measur	e:
Demilitarizatio	n:
No	
Fiig:	
A110a0	